

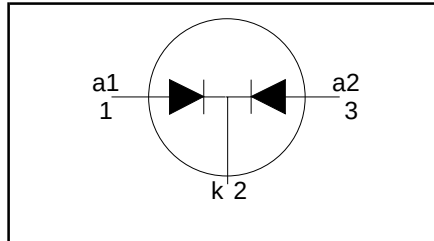
Rectifier diodes Schottky barrier

PBYL2525CT, PBYL2525CTB series

FEATURES

- Low forward volt drop
- Fast switching
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

SYMBOL



QUICK REFERENCE DATA

$$V_R = 20 \text{ V} / 25 \text{ V}$$

$$I_{O(AV)} = 25 \text{ A}$$

$$V_F \leq 0.43 \text{ V}$$

GENERAL DESCRIPTION

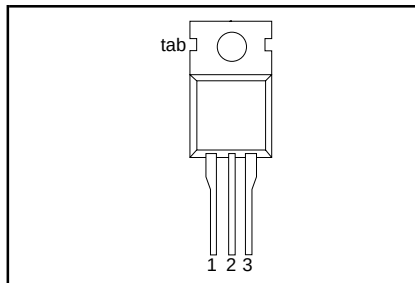
Dual schottky rectifier diodes intended for use as output rectifiers in low voltage, high frequency switched mode power supplies.

The PBYL2525CT series is supplied in the SOT78 (TO220AB) conventional leaded package.
The PBYL2525CTB series is supplied in the SOT404 surface mounting package.

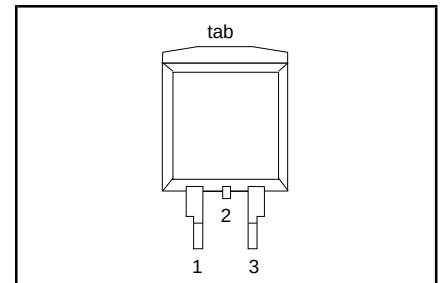
PINNING

PIN	DESCRIPTION
1	gate
2	drain ¹
3	source
tab	drain

SOT78 (TO220AB)



SOT404



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
V_{RRM}	Peak repetitive reverse voltage	$T_{mb} \leq 120 \text{ }^{\circ}\text{C}$	-	20CT 20	25CT 25	V
V_{RWM}	Working peak reverse voltage		-	20	25	V
V_R	Continuous reverse voltage		-	20	25	V
$I_{O(AV)}$	Average rectified output current (both diodes conducting)	square wave; $\delta = 0.5$; $T_{mb} \leq 119 \text{ }^{\circ}\text{C}$	-	25		A
I_{FRM}	Repetitive peak forward current per diode	square wave; $\delta = 0.5$; $T_{mb} \leq 119 \text{ }^{\circ}\text{C}$	-	25		A
I_{FSM}	Non-repetitive peak forward current per diode	$t = 10 \text{ ms}$	-	135		A
		$t = 8.3 \text{ ms}$	-	150		A
I_{RRM}	Peak repetitive reverse surge current per diode	sinusoidal; $T_j = 125 \text{ }^{\circ}\text{C}$ prior to surge; with reapplied $V_{RRM(max)}$ pulse width and repetition rate limited by T_{jmax}	-	1		A
T_j	Operating junction temperature		-	150		$^{\circ}\text{C}$
T_{stg}	Storage temperature		- 65	175		$^{\circ}\text{C}$

1. It is not possible to make connection to pin 2 of the SOT404 package.

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-mb}$	Thermal resistance junction to mounting base	per diode	-	-	3	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient	both diodes	-	-	2	K/W
		SOT78 package, in free air	-	60	-	K/W
		SOT404 package, pcb mounted, minimum footprint, FR4 board	-	50	-	K/W

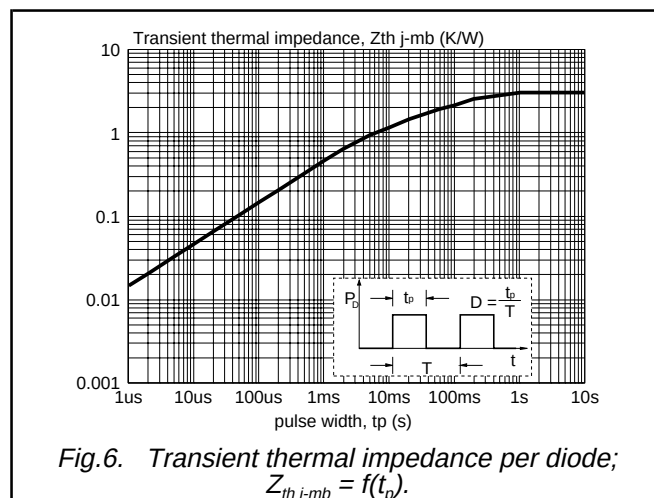
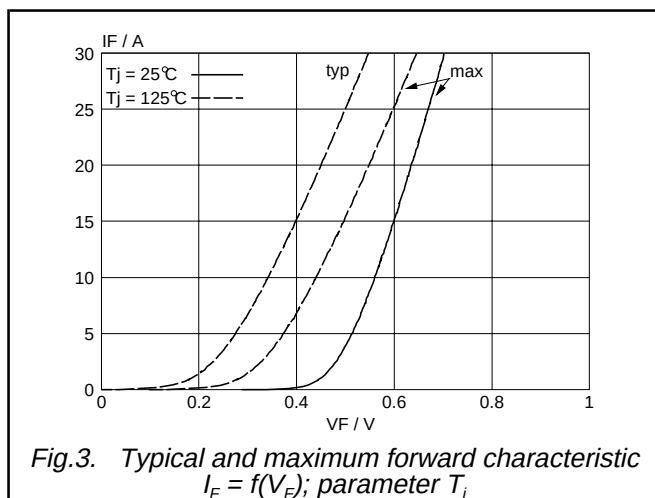
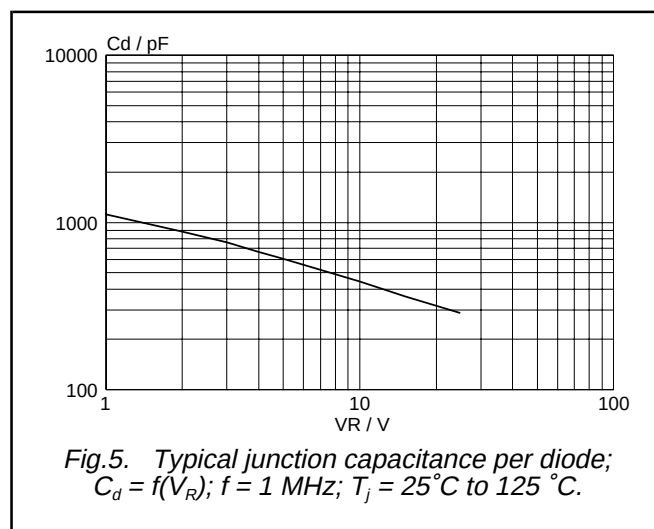
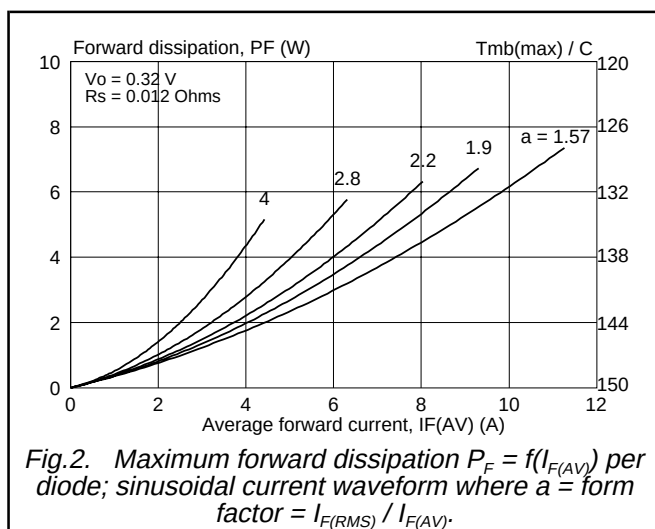
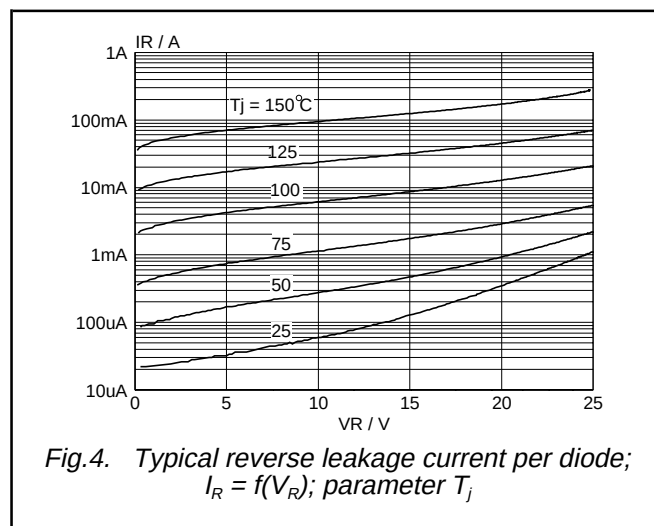
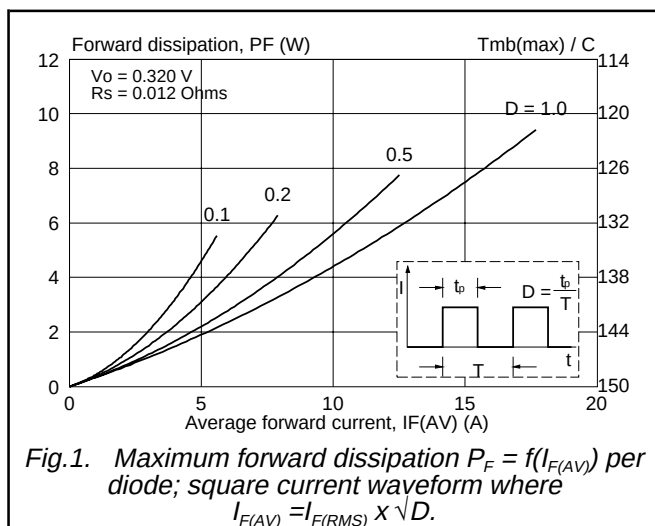
ELECTRICAL CHARACTERISTICS

All characteristics are per diode at $T_j = 25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	Forward voltage	$I_F = 12.5\text{ A}; T_j = 150^\circ\text{C}$	-	0.36	0.43	V
		$I_F = 12.5\text{ A}; T_j = 125^\circ\text{C}$	-	0.38	0.47	V
		$I_F = 25\text{ A}; T_j = 125^\circ\text{C}$	-	0.5	0.62	V
		$I_F = 25\text{ A}$	-	0.54	0.66	V
I_R	Reverse current	$V_R = V_{RWM}$	-	1	5	mA
		$V_R = V_{RWM}; T_j = 100^\circ\text{C}$	-	20	30	mA
C_d	Junction capacitance	$V_R = 5\text{ V}; f = 1\text{ MHz}; T_j = 25^\circ\text{C to } 125^\circ\text{C}$	-	600	-	pF

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MECHANICAL DATA

Dimensions in mm

Net Mass: 2 g

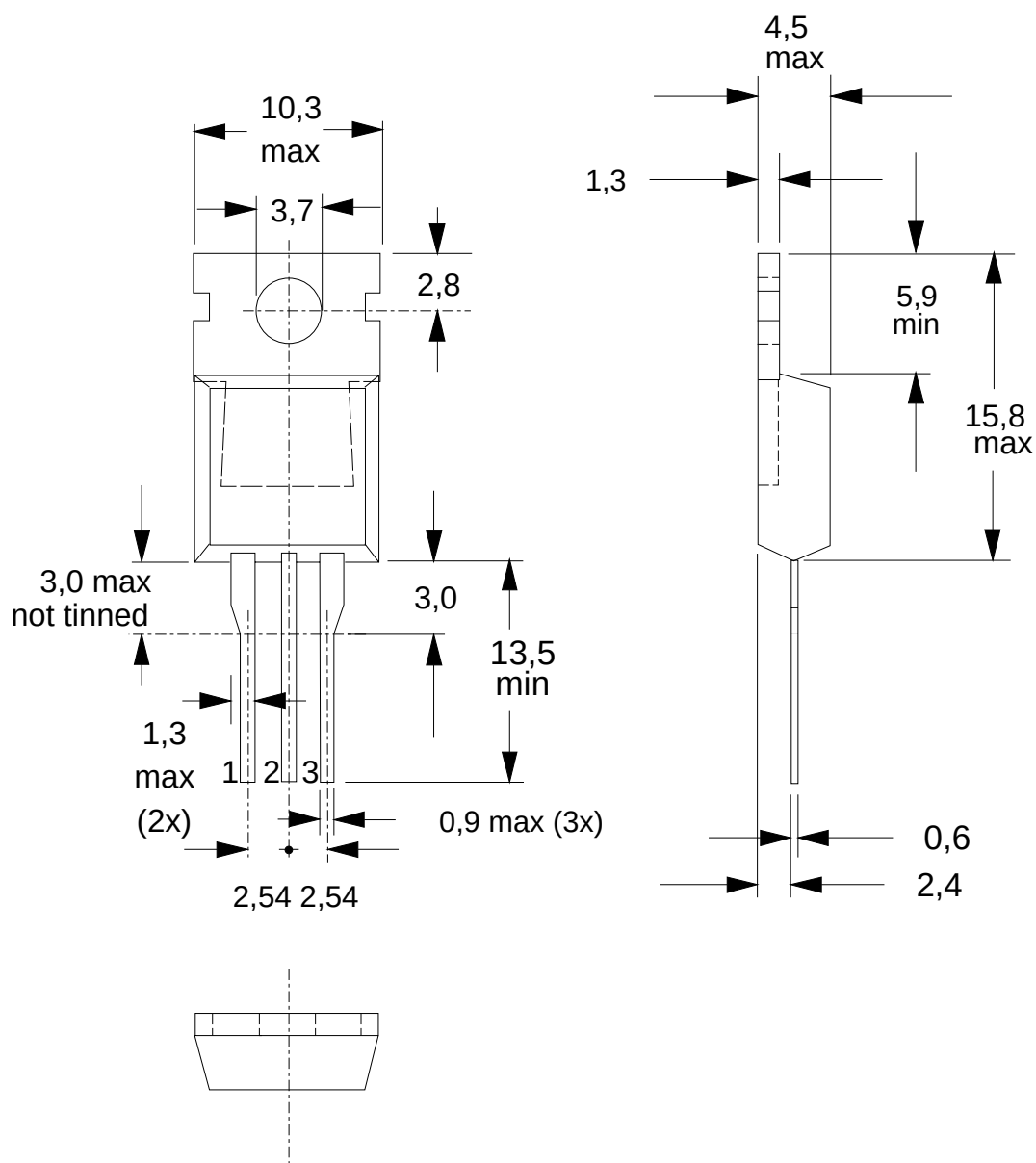


Fig.7. SOT78 (TO220AB); pin 2 connected to mounting base.

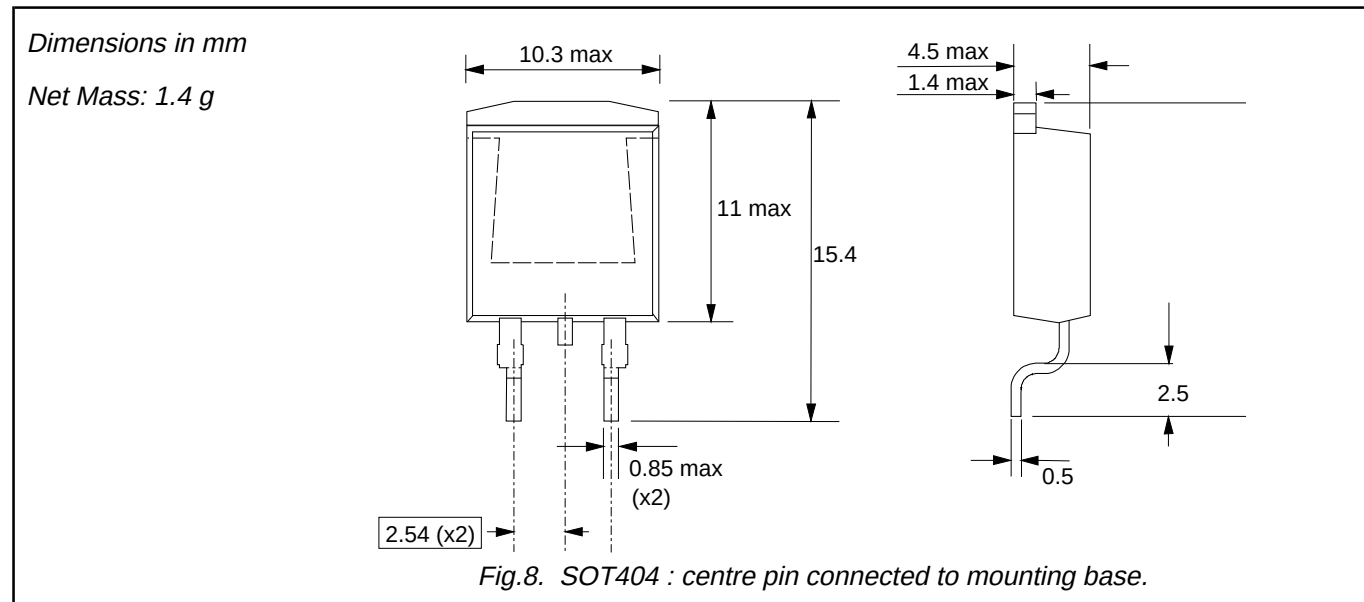
Notes

1. Refer to mounting instructions for SOT78 (TO220) envelopes.
2. Epoxy meets UL94 V0 at 1/8".

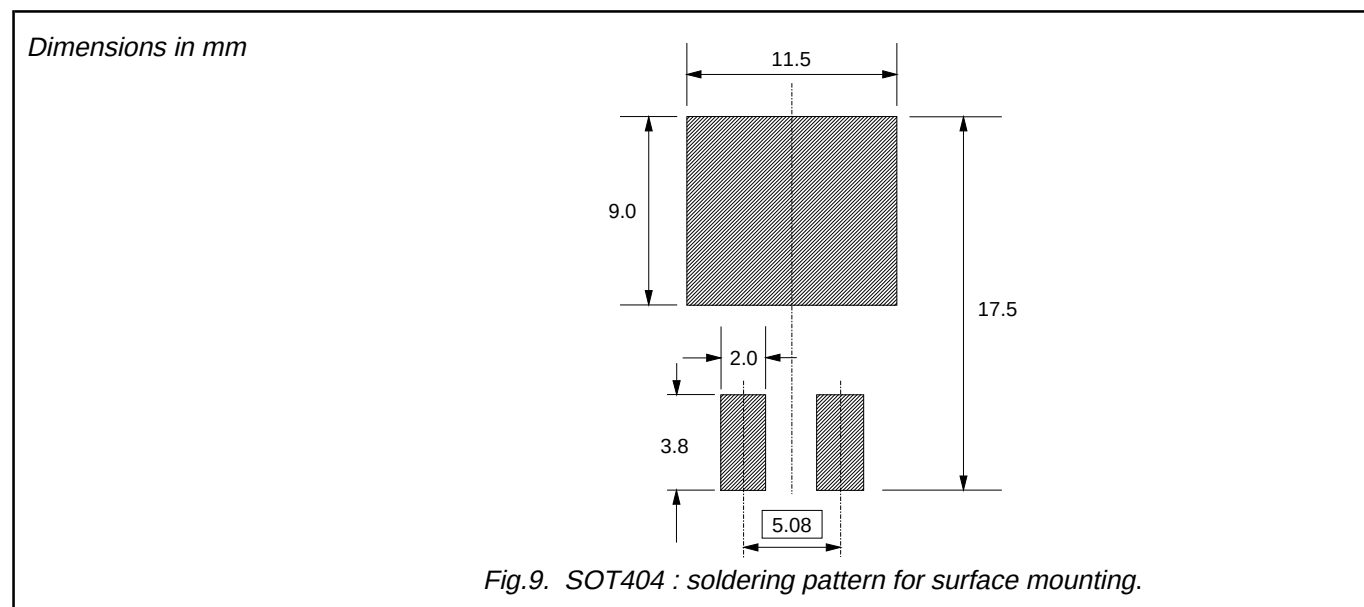
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MECHANICAL DATA



MOUNTING INSTRUCTIONS



Notes

1. Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	
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